

The listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Currently Amended) A semiconductor device comprising:
a pixel portion comprising a plurality of pixels;
a ~~signal-line-driver~~ first circuit; and
~~an output-switching~~ a second circuit,
wherein each of the plurality of pixels comprises a sensor portion and a liquid crystal element portion,
wherein the ~~signal-line-driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the ~~output-switching~~ second circuit, and
wherein the ~~output-switching~~ second circuit ~~outputs~~ is configured to select one of the sensor portion and the liquid crystal element portion, and output a pulse signal based on the timing signal to the one of the sensor portion and the liquid crystal element portion ~~different signals to the sensor portion and to the liquid crystal element portion.~~
2. (Currently Amended) A semiconductor device comprising:
a pixel portion comprising a plurality of pixels;
a ~~signal-line-driver~~ first circuit; and
~~an output-switching~~ a second circuit,
wherein each of the plurality of pixels comprises a sensor portion and a light emitting element portion,
wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit,
wherein the ~~signal-line-driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the first logical circuit and to the second logical circuit,

wherein one of the first logical circuit and the second logical circuit ~~outputs~~ is configured to output a first signal to the sensor portion, and the other ~~outputs~~ is configured to output a second signal to the light emitting element portion, and
wherein the first signal is different from the second signal.

3. (Currently Amended) A semiconductor device comprising:

a pixel portion comprising a plurality of pixels;

a ~~signal line driver~~ first circuit; and

~~an output switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a liquid crystal element portion,

wherein the ~~output switching~~ second circuit comprises a first logical circuit and a second logical circuit,

wherein the ~~signal line driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the first logical circuit and to the second logical circuit,

wherein one of the first logical circuit and the second logical circuit ~~outputs~~ is configured to output a first signal to the sensor portion, and the other ~~outputs~~ is configured to output a second signal to the liquid crystal element portion, and

wherein the first signal is different from the second signal.

4. (Currently Amended) A semiconductor device comprising:

a pixel portion comprising a plurality of pixels;

a ~~signal line driver~~ first circuit; and

~~an output switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a light emitting element portion,

wherein the sensor portion comprises a first TFT, and the light emitting element portion comprises a second TFT,

wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit;

wherein the first TFT is electrically connected to one of the first logical circuit and the second logical circuit, and the second TFT is electrically connected to the other,

wherein the ~~signal-line-driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the first logical circuit and to the second logical circuit,

wherein one of the first logical circuit and the second logical circuit ~~outputs~~ is configured to output a first signal to the first TFT, and the other ~~outputs~~ is configured to output a second signal to the second TFT, and

wherein the first signal is different from the second signal.

5. (Currently Amended) A semiconductor device comprising:

a pixel portion comprising a plurality of pixels;

a ~~signal-line-driver~~ first circuit; and

an ~~output-switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a liquid crystal element portion,

wherein the sensor portion comprises a first TFT, and the liquid crystal element portion comprises a second TFT,

wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit;

wherein the first TFT is electrically connected to one of the first logical circuit and the second logical circuit, and the second TFT is electrically connected to the other,

wherein the ~~signal-line-driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the first logical circuit and to the second logical circuit,

wherein one of the first logical circuit and the second logical circuit ~~outputs~~ is configured to output a first signal to the first TFT, and the other ~~outputs~~ is configured to output a second signal to the second TFT, and

wherein the first signal is different from the second signal.

6. (Currently Amended) A semiconductor device comprising:

a pixel portion having a plurality of pixels;

~~a signal-line driver~~ first circuit; and

~~an output-switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a light emitting element portion,

wherein the sensor portion comprises a first TFT, and the light emitting element portion comprises a second TFT,

wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit,

wherein the first circuit is configured to output a timing signal to the first logical circuit and to the second logical circuit,

wherein an image signal generated by the sensor portion is input to the light emitting element portion, and

wherein the second circuit is so configured that, when one of the first logical circuit and the second logical circuit outputs an off signal to ~~the first signal-line~~ one of the first TFT and the second TFT, [[and]] the other of the first logical circuit and the second logical circuit outputs a pulse signal to ~~the second signal-line~~ the other of the first TFT and the second TFT, and

~~wherein the first signal-line outputs the off signal to the first TFT, and the second signal-line outputs the pulse signal to the second TFT.~~

7. (Currently Amended) A semiconductor device comprising:

a pixel portion comprising a plurality of pixels;

~~a signal-line driver~~ first circuit;

~~an output-switching~~ a second circuit; and

one of a back light and a front light,
wherein each of the plurality of pixels comprises a sensor portion and a liquid crystal element portion,
wherein the sensor portion comprises a first TFT, and the liquid crystal element portion comprises a second TFT,
wherein the ~~output switching~~ second circuit comprises a first logical circuit and a second logical circuit,
wherein a first signal line is electrically connected to ~~one of~~ the first logical circuit and the second logical circuit, and a second signal line is electrically connected to the ~~other~~ the second logical circuit,
wherein the first TFT is electrically connected to the first signal line, and the second TFT is electrically connected to the second signal line,
wherein the ~~signal line driver~~ first circuit ~~outputs~~ is configured to output a timing signal to the first logical circuit and to the second logical circuit,
wherein an image signal generated by the sensor portion is input to ~~the light emitting element portion~~ the liquid crystal element portion,
wherein the second circuit is so configured that, when one of the first logical circuit and the second logical circuit outputs an off signal to ~~the first signal line~~ one of the first TFT and the second TFT, [[and]] the other of the first logical circuit and the second logical circuit outputs a pulse signal to ~~the second signal line~~ the other of the first TFT and the second TFT, and
~~wherein the first signal line outputs the off signal to the first TFT, and wherein the second signal line outputs the pulse signal to the second TFT.~~

8. (Original) A semiconductor device according to claim 2, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

9. (Original) A semiconductor device according to claim 3, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

10. (Original) A semiconductor device according to claim 4, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

11. (Original) A semiconductor device according to claim 5, wherein one of the first logical circuit and the second logical circuit is a NAND and the other is a NOR circuit.

12. (Original) A semiconductor device according to claim 6, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

13. (Original) A semiconductor device according to claim 7, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

14. (Original) A semiconductor device according to claim 2, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

15. (Original) A semiconductor device according to claim 3, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

16. (Original) A semiconductor device according to claim 4, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

17. (Original) A semiconductor device according to claim 5, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

18. (Original) A semiconductor device according to claim 6, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

19. (Original) A semiconductor device according to claim 7, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

20. (Original) A semiconductor device according to claim 2, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

21. (Original) A semiconductor device according to claim 3, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

22. (Original) A semiconductor device according to claim 4, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

23. (Original) A semiconductor device according to claim 5, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

24. (Original) A semiconductor device according to claim 6, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

25. (Original) A semiconductor device according to claim 7, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

26. (Original) A semiconductor device according to claim 2, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

27. (Original) A semiconductor device according to claim 3, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

28. (Original) A semiconductor device according to claim 4, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

29. (Original) A semiconductor device according to claim 5, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

30. (Original) A semiconductor device according to claim 6, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

31. (Original) A semiconductor device according to claim 7, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

32. (Currently Amended) A semiconductor device according to claim 6,
wherein the first logical circuit is electrically connected to the first TFT through a first signal line,

wherein the second logical circuit is electrically connected to the second TFT through a second signal line, and

~~wherein one of the first signal line and the second signal line is a selection signal line, and the other~~ the first signal line is a sensor selection signal line.

33. (Currently Amended) A semiconductor device according to claim 6,
wherein the first logical circuit is electrically connected to the first TFT through a first signal line,

wherein the second logical circuit is electrically connected to the second TFT through a second signal line, and

~~wherein one of the first signal line and the second signal line is a reset signal line, and the other~~ the first signal line is a sensor reset signal line.

34. (Currently Amended) A semiconductor device according to claim 6,
wherein the first logical circuit is electrically connected to the first TFT through a first signal line,

wherein the second logical circuit is electrically connected to the second TFT through a second signal line, and

wherein ~~one of the first signal line and~~ the second signal line is a selection signal line, and ~~the other~~ the first signal line is a sensor reset signal line.

35. (Currently Amended) A semiconductor device according to claim 6,
wherein the first logical circuit is electrically connected to the first TFT through a first signal line,

wherein the second logical circuit is electrically connected to the second TFT through a second signal line, and

wherein ~~one of the first signal line and~~ the second signal line is a reset signal line, and ~~the other~~ the first signal line is a sensor selection signal line.

36. (Original) A semiconductor device according to claim 7, wherein one of the first signal line and the second signal line is a liquid crystal selection signal line, and the other is a sensor selection signal line.

37. (Original) A semiconductor device according to claim 7, wherein one of the first signal line and the second signal line is a liquid crystal selection signal line, and the other is a sensor reset signal line.

38. (Original) A semiconductor device according to claim 4, wherein one of the first TFT and the second TFT is a selection TFT, and the other is a sensor selection TFT.

39. (Original) A semiconductor device according to claim 6, wherein one of the first TFT and the second TFT is a selection TFT, and the other is a sensor selection TFT.

40. (Original) A semiconductor device according to claim 4, wherein one of the first TFT and the second TFT is a selection TFT, and the other is a sensor reset TFT.

41. (Original) A semiconductor device according to claim 6, wherein one of the first TFT and the second TFT is a selection TFT, and the other is a sensor reset TFT.

42. (Original) A semiconductor device according to claim 4, wherein one of the first TFT and the second TFT is a reset TFT, and the other is a sensor reset TFT.

43. (Original) A semiconductor device according to claim 6, wherein one of the first TFT and the second TFT is a reset TFT, and the other is a sensor reset TFT.

44. (Original) A semiconductor device according to claim 4, wherein one of the first TFT and the second TFT is a reset TFT, and the other is a sensor selection TFT.

45. (Original) A semiconductor device according to claim 6, wherein one of the first TFT and the second TFT is a reset TFT, and the other is a sensor selection TFT.

46. (Original) A semiconductor device according to claim 5, wherein one of the first TFT and the second TFT is a liquid crystal selection TFT, and the other is a sensor selection TFT.

47. (Original) A semiconductor device according to claim 7, wherein one of the first TFT and the second TFT is a liquid crystal selection TFT, and the other is a sensor selection TFT.

48. (Original) A semiconductor device according to claim 5, wherein one of the first TFT and the second TFT is a liquid crystal selection TFT, and the other one is a sensor reset TFT.

49. (Original) A semiconductor device according to claim 7, wherein one of the first TFT and the second TFT is a liquid crystal selection TFT, and the other is a sensor reset TFT.

50. (Currently Amended) A semiconductor device according to claim 2, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

51. (Currently Amended) A semiconductor device according to claim 3, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

52. (Currently Amended) A semiconductor device according to claim 4, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

53. (Currently Amended) A semiconductor device according to claim 5, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

54. (Currently Amended) A semiconductor device according to claim 6, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

55. (Currently Amended) A semiconductor device according to claim 7, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

56. (Currently Amended) A semiconductor device according to claim 2, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

57. (Currently Amended) A semiconductor device according to claim 3, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

58. (Currently Amended) A semiconductor device according to claim 4, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

59. (Currently Amended) A semiconductor device according to claim 5, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

60. (Currently Amended) A semiconductor device according to claim 6, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

61. (Currently Amended) A semiconductor device according to claim 7, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

62. (Original) A semiconductor device according to claim 2, wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a reset TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

63. (Original) A semiconductor device according to claim 4, wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a reset TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

64. (Original) A semiconductor device according to claim 6, wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a reset TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

65. (Original) A semiconductor device according to claim 2 wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

66. (Original) A semiconductor device according to claim 4, wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

67. (Original) A semiconductor device according to claim 6, wherein each of the plurality of pixels comprises a light emitting element, a selection TFT, a driver TFT, a

photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, and a sensor reset TFT.

68. (Original) A semiconductor device according to claim 1, wherein each of the plurality of pixels comprises a liquid crystal element, a liquid crystal selection TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, a sensor reset TFT.

69. (Original) A semiconductor device according to claim 3, wherein each of the plurality of pixels comprises a liquid crystal element, a liquid crystal selection TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, a sensor reset TFT.

70. (Original) A semiconductor device according to claim 5, wherein each of the plurality of pixels comprises a liquid crystal element, a liquid crystal selection TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, a sensor reset TFT.

71. (Original) A semiconductor device according to claim 7, wherein each of the plurality of pixels comprises a liquid crystal element, a liquid crystal selection TFT, a photoelectric conversion element, a sensor selection TFT, a sensor driver TFT, a sensor reset TFT.

72. (Original) A semiconductor device according to claim 1, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

73. (Original) A semiconductor device according to claim 2, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

74. (Original) A semiconductor device according to claim 3, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

75. (Original) A semiconductor device according to claim 4, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

76. (Original) A semiconductor device according to claim 5, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

77. (Original) A semiconductor device according to claim 6, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

78. (Original) A semiconductor device according to claim 7, wherein each of the plurality of pixels comprises three light emitting elements and one photoelectric conversion element.

79. (Original) A display device using a semiconductor device according to claim 1.

2. 80. (Original) A display device using a semiconductor device according to claim
3. 81. (Original) A display device using a semiconductor device according to claim
4. 82. (Original) A display device using a semiconductor device according to claim
5. 83. (Original) A display device using a semiconductor device according to claim
6. 84. (Original) A display device using a semiconductor device according to claim
7. 85. (Original) A display device using a semiconductor device according to claim
86. (Original) A scanner using a semiconductor device according to claim 1.
87. (Original) A scanner using a semiconductor device according to claim 2.
88. (Original) A scanner using a semiconductor device according to claim 3.
89. (Original) A scanner using a semiconductor device according to claim 4.
90. (Original) A scanner using a semiconductor device according to claim 5.

91. (Original) A scanner using a semiconductor device according to claim 6.

92. (Original) A scanner using a semiconductor device according to claim 7.

93. (Original) A portable information terminal using a semiconductor device according to claim 1.

94. (Original) A portable information terminal using a semiconductor device according to claim 2.

95. (Original) A portable information terminal using a semiconductor device according to claim 3.

96. (Original) A portable information terminal using a semiconductor device according to claim 4.

97. (Original) A portable information terminal using a semiconductor device according to claim 5.

98. (Original) A portable information terminal using a semiconductor device according to claim 6.

99. (Original) A portable information terminal using a semiconductor device according to claim 7.

100. (Currently Amended) A semiconductor device comprising:
a pixel portion comprising a plurality of pixels;
a ~~signal line driver~~ first circuit; and

~~an output switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a light emitting element portion, ~~[[and]]~~

wherein the first circuit is configured to output a timing signal to the second circuit,

wherein the ~~output switching~~ second circuit is electrically connected to the sensor portion and to the light emitting element portion, and

wherein the second circuit is configured to select one of the sensor portion and the light emitting element portion depending on a control signal, and output a pulse signal based on the timing signal to the one of the sensor portion and the light emitting element portion.

101. (Currently Amended) A semiconductor device comprising:

a pixel portion comprising a plurality of pixels

a ~~signal line driver~~ first circuit; and

~~an output switching~~ a second circuit,

wherein each of the plurality of pixels comprises a sensor portion and a liquid crystal element portion, ~~[[and]]~~

wherein the first circuit is configured to output a timing signal to the second circuit,

wherein the ~~output switching~~ second circuit is electrically connected to the sensor portion and to the liquid crystal element portion, and

wherein the second circuit is configured to select one of the sensor portion and the liquid crystal element portion depending on a control signal, and output a pulse signal based on the timing signal to the one of the sensor portion and the liquid crystal element portion.

102. (Currently Amended) A semiconductor device according to claim 100, wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit, and one of the first logical circuit and the second logical circuit is electrically connected to the sensor portion and the other is electrically connected to the light emitting element portion.

103. (Currently Amended) A semiconductor device according to claim 101, wherein the ~~output-switching~~ second circuit comprises a first logical circuit and a second logical circuit, and one of the first logical circuit and the second logical circuit is electrically connected to the sensor portion and the other is electrically connected to the liquid crystal element portion.

104. (Currently Amended) A semiconductor device according to ~~claim 100~~ claim 102, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

105. (Currently Amended) A semiconductor device according to ~~claim 101~~ claim 103, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is a NOR circuit.

106. (Currently Amended) A semiconductor device according to ~~claim 100~~ claim 102, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

107. (Currently Amended) A semiconductor device according to ~~claim 101~~ claim 103, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is a NOR circuit.

108. (Currently Amended) A semiconductor device according to ~~claim 100~~ claim 102, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

109. (Currently Amended) A semiconductor device according to ~~claim 104~~ claim 103, wherein one of the first logical circuit and the second logical circuit is a NAND circuit and the other is an OR circuit.

110. (Currently Amended) A semiconductor device according to ~~claim 100~~ claim 102, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

111. (Currently Amended) A semiconductor device according to ~~claim 104~~ claim 103, wherein one of the first logical circuit and the second logical circuit is an AND circuit and the other is an OR circuit.

112. (Currently Amended) A semiconductor device according to claim 102, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

113. (Currently Amended) A semiconductor device according to claim 103, wherein an output terminal of the first logical circuit is electrically connected to at least one inverter circuit.

114. (Currently Amended) A semiconductor device according to claim 102, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

115. (Currently Amended) A semiconductor device according to claim 103, wherein an output terminal of the second logical circuit is electrically connected to at least one inverter circuit.

116. (Original) A display device using a semiconductor device according to claim 100.

117. (Original) A display device using a semiconductor device according to claim 101.

118. (Original) A scanner using a semiconductor device according to claim 100.

119. (Original) A scanner using a semiconductor device according to claim 101.

120. (Original) A portable information terminal using a semiconductor device according to claim 100.

121. (Original) A portable information terminal using a semiconductor device according to claim 101.

122. (New) A semiconductor device according to claim 1, wherein the first circuit comprises shift register.

123. (New) A semiconductor device according to claim 2, wherein the first circuit comprises a shift register.

124. (New) A semiconductor device according to claim 3, wherein the first circuit comprises a shift register.

125. (New) A semiconductor device according to claim 4, wherein the first circuit comprises a shift register.

126. (New) A semiconductor device according to claim 5, wherein the first circuit comprises a shift register.

127. (New) A semiconductor device according to claim 6, wherein the first circuit comprises shift register.

128. (New) A semiconductor device according to claim 7, wherein the first circuit comprises a shift register.

129. (New) A semiconductor device according to claim 100, wherein the first circuit comprises a shift register.

130. (New) A semiconductor device according to claim 101, wherein the first circuit comprises a shift register.